



74AUP2G3404 BUFFER AND INVERTER

Description

The Advanced Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

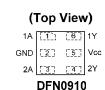
The 74AUP2G3404 has one buffer and one inverter. Both gates have push-pull outputs designed for operation over a power supply range of 0.8V to 3.6V. The device is fully specified for partial power down applications using $I_{\rm OFF}$. The $I_{\rm OFF}$ circuitry disables the output preventing damaging current backflow when the device is powered down

Pin Assignments

(Top View)







Features

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- ± 4mA Output Drive at 3.0V
- Low Static power consumption
 - I_{CC} < 0.9µA
- Low Dynamic Power Consumption
 - C_{PD} = 6pF Typical at 3.6V
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time. The hysteresis is typically 250mV at V_{CC} = 3.0V
- I_{OFF} Supports Partial-Power-Down Mode Operation
 - ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114-)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Leadless packages per JESD30E

Notes:

- DFN1410 denoted as X2-DFN1410-6
- DFN1010 denoted as X2-DFN1010-6
- DFN0910 denoted as X2-DFN0910-6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

- Suited for battery and low power needs
- · Wide array of products such as:
 - PCs, networking, Notebooks, Netbooks, PDAs
 - Tablet Computers, E-Readers
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box
 - Cell Phones, Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

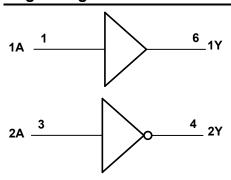
Click for Ordering Information



Pin Descriptions

| Pin Name | Pin No. | Function |
|-----------------|---------|----------------|
| 1A | 1 | Data Input |
| GND | 2 | Ground |
| 2A | 3 | Data Input |
| 2Y | 4 | Data Output |
| V _{CC} | 5 | Supply Voltage |
| 1Y | 6 | Data Output |

Logic Diagram



Function Tables

| Input | Output |
|-------|--------|
| 1A | 1Y |
| Н | Н |
| L | L |

| Input | Output |
|-------|--------|
| 2A | 2Y |
| Н | L |
| L | Н |



Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

| Symbol | Description | Rating | Unit |
|------------------|--|------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | KV |
| ESD CDM | Charged Device Model ESD Protection | 1 | KV |
| ESD MM | Machine Model ESD Protection | 200 | V |
| V _{CC} | Supply Voltage Range | -0.5 to 4.6 | V |
| VI | Input Voltage Range | -0.5 to 4.6 | V |
| Vo | Voltage applied to output in high or low state | -0.5 to V _{CC} +0.5 | V |
| I _{IK} | Input Clamp Current V _I < 0 | 50 | mA |
| Іок | Output Clamp Current (Vo < 0) | -50 | mA |
| Io | Continuous Output Current (V _O = 0 to V _{CC}) | ±20 | mA |
| lcc | Continuous Current Through V _{CC} | 50 | mA |
| I _{GND} | Continuous Current Through GND | -50 | mA |
| TJ | Operating Junction Temperature | -40 to +150 | °C |
| T _{STG} | Storage Temperature | -65 to +150 | °C |

Note:

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

| Symbol | | Parameter | Min | Max | Unit |
|-----------------|------------------------------------|--------------------------------|-----|------|------|
| V_{CC} | Operating Voltage | _ | 0.8 | 3.6 | V |
| V_{I} | Input Voltage | | 0 | 3.6 | V |
| Vo | Output Voltage | | 0 | Vcc | V |
| | | V _{CC} = 0.8V | _ | -20 | μA |
| | | V _{CC} = 1.1V | _ | -1.1 | |
| I _{OH} | High Loyal Output Current | V _{CC} = 1.4V | _ | -1.7 | |
| | High-Level Output Current | V _{CC} = 1.65V | _ | -1.9 | mA |
| | | V _{CC} = 2.3V | _ | -3.1 | |
| | | V _{CC} = 3.0V | _ | -4 | |
| | | V _{CC} = 0.8V | _ | 20 | μA |
| | | V _{CC} = 1.1V | _ | 1.1 | |
| | Low-Level Output Current | V _{CC} = 1.4V | _ | 1.7 | |
| l _{OL} | Low-Level Output Current | V _{CC} = 1.65V | _ | 1.9 | mA |
| | | V _{CC} = 2.3V | _ | 3.1 | |
| | | V _{CC} = 3.0V | _ | 4 | |
| Δt/ΔV | Input transition rise or fall rate | V _{CC} = 0.8V to 3.6V | _ | 200 | ns/V |
| T _A | Operating free-air temperature | _ | -40 | +125 | °C |

Note: 5. Unused inputs should be held at V_{CC} or Ground.

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Cymphol | Parameter | Test Conditions | V | T _A = - | +25°C | T _A =-40 | to +85°C | Unit | |
|------------------|---------------------------|--|-----------------|------------------------|------------------------|------------------------|------------------------|------|--|
| Symbol | Parameter | lest Conditions | V _{CC} | Min | Max | Min | Max | Unit | |
| | | _ | 0.8V to 1.65V | 0.80 X V _{CC} | ı | 0.80 X V _{CC} | - | | |
| VIH | High-Level Input | | 1.65V to 1.95V | 0.65 X V _{CC} | I | 0.65 X V _{CC} | ı | V | |
| VIH | Voltage | | 2.3V to 2.7V | 1.6 | I | 1.6 | ı | V | |
| | | _ | 3.0V to 3.6V | 2.0 | | 2.0 | - | | |
| | | _ | 0.8V to 1.65V | _ | 0.30 X V _{CC} | _ | 0.30 X V _{CC} | | |
| VII | Low-Level Input | _ | 1.65V to 1.95V | _ | 0.35 X V _{CC} | _ | 0.35 X V _{CC} | V | |
| ۷IL | Voltage | _ | 2.3V to 2.7V | _ | 0.7 | _ | 0.7 | v | |
| | | _ | 3.0V to 3.6V | _ | 0.9 | _ | 0.9 | | |
| | | I _{OH} = -20μA | 0.8V to 3.6V | V _{CC} - 0.1 | _ | V _{CC} – 0.1 | _ | | |
| | | I _{OH} = -1.1mA | 1.1V | 0.75 X V _{CC} | _ | 0.7 X V _{CC} | _ | | |
| High-Level | $I_{OH} = -1.7 \text{mA}$ | 1.4V | 1.11 | _ | 1.03 | _ |] | | |
| | $I_{OH} = -1.9 \text{mA}$ | 1.65V | 1.32 | _ | 1.3 | _ | V | | |
| VOH | Output Voltage | I _{OH} = -2.3mA | 2.3V | 2.05 | _ | 1.97 | _ | · | |
| | | I _{OH} = -3.1mA | 2.5 V | 1.9 | _ | 1.85 | _ | | |
| | | $I_{OH} = -2.7 \text{mA}$ | 3V | 2.72 | _ | 2.67 | _ | | |
| | | I _{OH} = -4mA | 5 V | 2.6 | _ | 2.55 | _ | | |
| | | I _{OL} = 20μA | 0.8V to 3.6V | _ | 0.1 | _ | 0.1 | | |
| | | I _{OL} = 1.1mA | 1.1V | _ | 0.3 X V _{CC} | _ | 0.3 X V _{CC} | | |
| | | I _{OL} = 1.7mA | 1.4V | _ | 0.31 | _ | 0.37 | | |
| VoL | Low-Level Input | I _{OL} = 1.9mA | 1.65V | _ | 0.31 | _ | 0.35 | V | |
| VOL | Voltage | $I_{OL} = 2.3 \text{mA}$ | 2.3V | _ | 0.31 | _ | 0.33 | V | |
| | | I _{OL} = 3.1mA | 2.5 V | _ | 0.44 | _ | 0.45 | | |
| | | $I_{OL} = 2.7 \text{mA}$ | 3V | _ | 0.31 | _ | 0.33 | | |
| | | I _{OL} = 4mA | 3 V | _ | 0.44 | _ | 0.45 | | |
| lı | Input Current | A or B Input | 0V to 3.6V | _ | ± 0.1 | _ | ± 0.5 | μA | |
| I _{OFF} | Power Down | V_1 or $V_0 = 0V$ to 3.6V | 0V | _ | ± 0.2 | _ | ± 0.6 | μΑ | |
| ΔI_{OFF} | Delta Power | V_I or $V_O = 0V$ to 3.6V | 0V to 0.2V | _ | ± 0.2 | _ | ± 0.6 | μA | |
| Icc | Supply Current | $V_I = GND \text{ or } V_{CC}, I_O = 0$ | 0.8V to 3.6V | _ | 0.5 | _ | 0.9 | μA | |
| ΔI_{CC} | Additional Supply | One input at V _{CC} –0.6V Other | 3.3V | _ | 40 | _ | 50 | μΑ | |



Electrical Characteristics (cont.) (@T_A = +25°C, unless otherwise specified.)

| Symbol | Parameter | Test Conditions | V | T _A = -40 | to 125°C | Unit |
|-------------------|-------------------------------------|--|-----------------|------------------------|------------------------|---------------------------------------|
| Syllibol | Faranietei | rest conditions | V _{CC} | Min | Max | Unit |
| | | _ | 0.8V to 1.65V | 0.80 X V _{CC} | _ | |
| V _{IH} | High-Level Input Voltage | _ | 1.65V to 1.95V | 0.70 X V _{CC} | _ | V |
| VIH | High-Level Input Voltage | _ | 2.3V to 2.7V | 1.6 | _ | V |
| | | _ | 3.0V to 3.6V | 2.0 | _ | |
| | | _ | 0.8V to 1.65V | _ | 0.25 X V _{CC} | |
| VIL | Low-Level Input Voltage | _ | 1.65V to 1.95V | _ | 0.30 X V _{CC} | V |
| VIL | Low-Level input voltage | _ | 2.3V to 2.7V | _ | 0.7 | V |
| | | _ | 3.0V to 3.6V | _ | 0.9 | |
| | | $I_{OH} = -20\mu A$ | 0.8V to 3.6V | V _{CC} – 0.11 | _ | |
| | | $I_{OH} = -1.1$ mA | 1.1V | 0.6 X V _{CC} | _ | |
| | High-Level Output Voltage | I _{OH} = -1.7mA | 1.4V | 0.93 | _ | |
| ., | | I _{OH} = -1.9mA | 1.65V | 1.17 | _ | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ |
| Voн | | I _{OH} = -2.3mA | 2.21/ | 1.77 | _ | V |
| | | I _{OH} = -3.1mA | 2.3V | 1.67 | _ | |
| | | I _{OH} = -2.7mA | 21/ | 2.40 | _ | |
| | | I _{OH} = -4mA | 3V | 2.30 | _ | |
| | | I _{OL} = 20μA | 0.8V to 3.6V | _ | 0.11 | |
| | | I _{OL} = 1.1mA | 1.1V | _ | 0.33 X V _{CC} | |
| | | I _{OL} = 1.7mA | 1.4V | _ | 0.41 | |
| | | I _{OL} = 1.9mA | 1.65V | _ | 0.39 | ., |
| V_{OL} | Low-Level Input Voltage | I _{OL} = 2.3mA | 2.01 | _ | 0.36 | V |
| | | I _{OL} = 3.1mA | 2.3V | _ | 0.50 | |
| | | I _{OL} = 2.7mA | | _ | 0.36 | |
| | | I _{OL} = 4mA | 3V | _ | 0.50 | |
| II | Input Current | A or B Input, V _I = GND to 3.6V | 0V to 3.6V | _ | ± 0.75 | μA |
| l _{OFF} | Power Down Leakage Current | V_1 or $V_0 = 0V$ to 3.6V | 0V | _ | ± 1.0 | μA |
| Δl _{OFF} | Delta Power Down Leakage Current | V _I or V _O = 0V to 3.6V | 0V to 0.2V | _ | ± 2.5 | μA |
| Icc | Supply Current | $V_1 = GND \text{ or } V_{CC}, I_0 = 0$ | 0.8V to 3.6V | _ | 1.4 | μA |
| ΔI _{CC} | Additional Supply Current | Input at V_{CC} –0.6V Other input at V_{CC} or GND | 3.3V | _ | 75 | μА |

Operating and Package Characteristics

T_A = +25°C

| | Parameter | Test Conditions | Vcc | Тур | Unit |
|--------------|-------------------------------|-----------------------|--------------|-----|------|
| | | | 0.8V | 5.1 | |
| | | | 1.2V ± 0.1V | 5.2 | |
| 0 | Dower dissination canacitance | f = 1MHz | 1.5V ± 0.1V | 5.2 | pF |
| $C_{\sf pd}$ | Power dissipation capacitance | No Load | 1.8V ± 0.15V | 5.5 | |
| | | | 2.5V ± 0.2V | 5.7 | |
| | | | 3.3V ± 0.3V | 6.0 | |
| Cı | Input Capacitance | $V_i = V_{CC}$ or GND | 0V or 3.3V | 2.0 | pF |
| Co | Output Capacitance | $V_O = V_{CC}$ or GND | 0V | 3.5 | pF |



Switching Characteristics

C_L = 5pF see Figure 1

| Parameter | From | TO OUTPUT | V _{CC} | T _A = +25°C | | | $T_A = -40 \text{ to } +85^{\circ}\text{C}$ | | T _A = -40 to | Unit | |
|-----------------|-------|--------------|-----------------|------------------------|------|------|---|------|-------------------------|------|-------|
| Faranietei | Input | | V CC | Min | Тур | Max | Min | Max | Min | Max | Oilit |
| | | | V8.0 | | 16.0 | | | | | | |
| | А | Y | 1.2V ± 0.1V | 2.4 | 5.0 | 10.3 | 2.0 | 11.4 | 2.0 | 12.6 | |
| | | | 1.5V ± 0.1V | 1.8 | 3.6 | 6.4 | 1.6 | 7.4 | 1.6 | 8.2 | |
| t _{pd} | | | 1.8V ± 0.15V | 1.5 | 2.9 | 5.0 | 1.4 | 5.9 | 1.4 | 6.5 | ns |
| | | | 2.5V ± 0.2V | 1.2 | 2.4 | 3.9 | 1.1 | 4.5 | 1.1 | 5.0 | |
| | | | 3.3V ± 0.3V | 1.1 | 2.1 | 3.2 | 1.0 | 3.9 | 1.0 | 4.3 | |

C_L = 10pF see Figure 1

| Parameter | From | _ | V _{CC} | 1 | T _A = +25°C | | T _A = -40 to +85°C | | T _A = -40 to +125°C | | Unit |
|-----------------|-------|---|-----------------|-----|------------------------|------|-------------------------------|------|--------------------------------|------|-------|
| rarameter | Input | | | Min | Тур | Max | Min | Max | Min | Max | Offic |
| | | | V8.0 | | 19.8 | | | | | | |
| | | | 1.2V ± 0.1V | 2.8 | 5.9 | 12.2 | 2.3 | 13.7 | 2.3 | 15.1 | ns |
| | ^ | V | 1.5V ± 0.1V | 2.3 | 4.2 | 7.5 | 1.9 | 8.7 | 1.9 | 9.6 | |
| t _{pd} | Α | Ţ | 1.8V ± 0.15V | 2.0 | 3.5 | 5.9 | 1.7 | 7.0 | 1.7 | 7.7 | |
| | | | 2.5V ± 0.2V | 1.7 | 2.9 | 4.6 | 1.5 | 5.4 | 1.5 | 6.0 | |
| | | | 3.3V ± 0.3V | 1.6 | 2.7 | 3.8 | 1.4 | 4.5 | 1.4 | 5.1 | |

C_L = 15pF see Figure 1

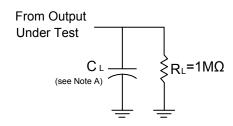
| Parameter | From | то | V | ٦ | Γ _A = +25°0 | 3 | $T_A = -40 \text{ to } +85^{\circ}\text{C}$ | | $T_A = -40 \text{ to}$ | +125°C | Unit |
|-------------------|--------|-----|--------------|-----|------------------------|------|---|------|------------------------|--------|------|
| Input | OUTPUT | Vcc | Min | Тур | Max | Min | Max | Min | Max | Ullit | |
| | | | V8.0 | | 23.3 | | | | | | |
| | | Y | 1.2V ± 0.1V | 3.2 | 6.7 | 13.0 | 2.6 | 15.8 | 2.6 | 17.4 | |
| 4 | ^ | | 1.5V ± 0.1V | 2.6 | 4.7 | 8.6 | 2.2 | 10.0 | 2.2 | 11.0 | |
| t _{pd} A | А | | 1.8V ± 0.15V | 2.3 | 4.0 | 6.7 | 2.0 | 8.0 | 2.0 | 8.8 | ns |
| | | | 2.5V ± 0.2V | 2.1 | 3.3 | 5.1 | 1.8 | 6.1 | 1.8 | 6.8 | |
| | | | 3.3V ± 0.3V | 2.0 | 3.1 | 4.2 | 1.6 | 5.0 | 1.6 | 5.5 | 1 |

C_L = 30pF see Figure 1

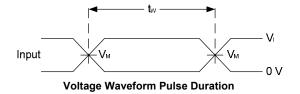
| Parameter | From | то | V | - | T _A = +25°C | | | to +85°C | T _A = -40 to | Unit | |
|-----------------|-------|--------|-----------------|------|------------------------|------|-----|----------|-------------------------|------|-------|
| Inpu | Input | OUTPUT | V _{CC} | Min | Тур | Max | Min | Max | Min | Max | Ullit |
| | | 0.8V | | 33.6 | | | | | | | |
| | | Y | 1.2V ± 0.1V | 4.4 | 8.9 | 16.3 | 3.6 | 19.0 | 3.6 | 20.9 | ns |
| | | | 1.5V ± 0.1V | 3.6 | 6.3 | 10.8 | 3.2 | 12.9 | 3.2 | 14.2 | |
| t _{pd} | Α | | 1.8V ± 0.15V | 3.2 | 5.3 | 9.0 | 2.9 | 10.5 | 2.9 | 11.6 | |
| | | | 2.5V ± 0.2V | 2.4 | 4.5 | 6.5 | 2.6 | 7.6 | 2.6 | 8.5 | |
| | | | 3.3V ± 0.3V | 2.2 | 4.2 | 5.6 | 2.2 | 6.2 | 2.2 | 7.2 | |

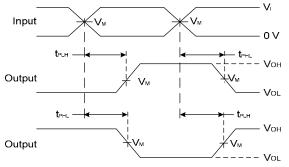


Parameter Measurement Information



| ., | Inputs | | V | |
|-----------------|-----------------|--------------------------------|--------------------|-----------------|
| V _{CC} | VI | t _r /t _f | V_{M} | CL |
| 0.8 V | V _{CC} | ≤3ns | V _{CC} /2 | 5, 10, 15, 30pF |
| 1.2V±0.1V | V _{CC} | ≤3ns | V _{CC} /2 | 5, 10, 15, 30pF |
| 1.5V±0.1V | V _{CC} | ≤3ns | V _{CC} /2 | 5, 10, 15, 30pF |
| 1.8V±0.15V | V _{CC} | ≤3ns | V _{CC} /2 | 5, 10, 15, 30pF |
| 2.5V±0.2V | V _{CC} | ≤3ns | V _{CC} /2 | 5, 10, 15, 30pF |
| 3.3V±0.3V | V _{CC} | ≤3ns | V _{CC} /2 | 5, 10, 15, 30pF |





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

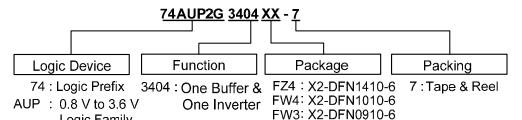
Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
 C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



Ordering Information



Logic Family 2G: Dual Gate

| Device | Packaging Packaging | 7" Tape and Reel | | |
|------------------|---------------------|------------------|------------------|--------------------|
| Device | Package Code | (Note 7) | Quantity | Part Number Suffix |
| 74AUP2G3404FZ4-7 | FZ4 | X2-DFN1410-6 | 5000/Tape & Reel | -7 |
| 74AUP2G3404FW4-7 | FW4 | X2-DFN1010-6 | 5000/Tape & Reel | -7 |
| 74AUP2G3404FW3-7 | FW3 | X2-DFN0910-6 | 5000/Tape & Reel | -7 |

Note:

- 7. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf
- 8. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information

(1) X2-DFN1410-6, X2-DFN1010-6, X2-DFN0910-6

(Top View)

XX XX: Identification Code \overline{Y} : Year: 0~9

Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

a~z: 27~52 week; z represents

Output

Description:

A value of the content of th

52 and 53 week X: A~Z: Internal code

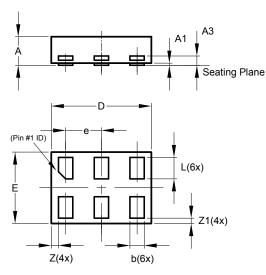
| Part Number | Package | Identification Code |
|----------------|--------------|---------------------|
| 74AUP2G3404FZ4 | X2-DFN1410-6 | RU |
| 74AUP2G3404FW4 | X2-DFN1010-6 | SU |
| 74AUP2G3404FW3 | X2-DFN0910-6 | MU |



Package Outline Dimensions (All dimensions in mm.)

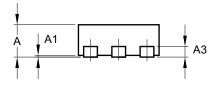
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

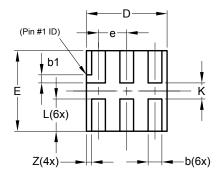
(1) Package Type X2-DFN1410-6



| X2-DFN1410-6 | | | |
|----------------------|-------|-------|-------|
| Dim | Min | Max | Тур |
| Α | _ | 0.40 | 0.39 |
| A1 | 0.00 | 0.05 | 0.02 |
| А3 | | | 0.13 |
| b | 0.15 | 0.25 | 0.20 |
| D | 1.35 | 1.45 | 1.40 |
| Е | 0.95 | 1.05 | 1.00 |
| е | - | - | 0.50 |
| L | 0.25 | 0.35 | 0.30 |
| Z | | | 0.10 |
| Z 1 | 0.045 | 0.105 | 0.075 |
| All Dimensions in mm | | | |

(2) Package Type: X2-DFN1010-6





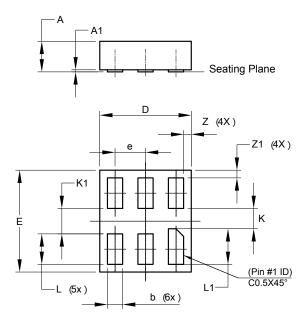
| X2-DFN1010-6 | | | | |
|----------------------|------|------|-------|--|
| Dim | Min | Max | Тур | |
| Α | | 0.40 | 0.39 | |
| A 1 | 0.00 | 0.05 | 0.02 | |
| A3 | _ | _ | 0.13 | |
| b | 0.14 | 0.20 | 0.17 | |
| b1 | 0.05 | 0.15 | 0.10 | |
| D | 0.95 | 1.05 | 1.00 | |
| П | 0.95 | 1.05 | 1.00 | |
| е | _ | _ | 0.35 | |
| L | 0.35 | 0.45 | 0.40 | |
| K | 0.15 | | | |
| Z | _ | | 0.065 | |
| All Dimensions in mm | | | | |



Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(3) Package Type: X2-DFN0910-6



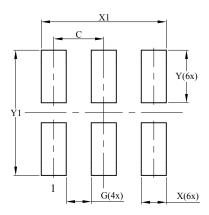
| X2-DFN0910-6 | | | | |
|----------------------|------|------|-------|--|
| Dim | Min | Max | Тур | |
| Α | - | 0.35 | 0.30 | |
| A 1 | 0 | 0.03 | 0.02 | |
| b | 0.10 | 0.20 | 0.15 | |
| D | 0.85 | 0.95 | 0.90 | |
| Е | 0.95 | 1.05 | 1.00 | |
| е | - | - | 0.30 | |
| K | 0.20 | 1 | - | |
| K1 | 0.25 | - | - | |
| L | 0.25 | 0.35 | 0.30 | |
| L1 | 0.30 | 0.40 | 0.35 | |
| Z | - | - | 0.075 | |
| Z 1 | - | - | 0.075 | |
| All Dimensions in mm | | | | |



Suggested Pad Layout

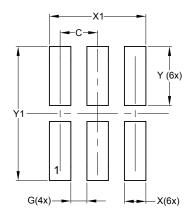
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type X2-DFN1410-6



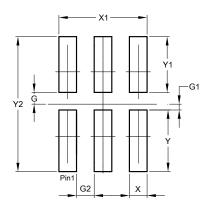
| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.500 |
| G | 0.250 |
| X | 0.250 |
| X1 | 1.250 |
| Y | 0.525 |
| Y1 | 1.250 |

(2) Package Type: X2-DFN1010-6



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.350 |
| G | 0.150 |
| Х | 0.200 |
| X1 | 0.900 |
| Y | 0.550 |
| Y1 | 1.250 |

(3) Package Type: X2-DFN0910-6



| Dimensions | Value (in mm) |
|------------|------------------|
| G | 0.100 |
| G1 | 0.050 |
| G2 | 0.150 |
| Х | 0.150 |
| X1 | 0.750 |
| Y | 0.525 |
| Y1 | 0.475 |
| Y2 | 1.150 |



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